## Molecular plating of uranium on thin aluminum backings\*

D. Liebe<sup>1</sup>, K. Eberhardt<sup>1</sup>, W. Hartmann<sup>2</sup>, A. Hübner<sup>2</sup>, B. Kindler<sup>2</sup>, J.V. Kratz<sup>1</sup>, B. Lommel<sup>2</sup>, J. Steiner<sup>2</sup>, P. Thörle<sup>1</sup>

<sup>1</sup>Institut für Kernchemie, Johannes-Gutenberg-Universität Mainz (UMZ), Germany <sup>2</sup>Gesellschaft für Schwerionenforschung, GSI, Darmstadt, Germany

Molecular plating is widely used for the deposition of lanthanide and actinide compounds on thin metallic backing foils [1]. At GSI and UMZ, this method has been previously applied on Ti or Be foils. Within the requirements of the TASCA-Project (TransActinide Separator and Chemistry Apparatus) very thin foils of AI (2-10µm) as backing material have been proposed [2].

The general usability of very thin AI was investigated by a test series with Gd and U. For these tests, plating conditions were adopted unchanged from previous practices [3]. Although AI foils of less than 10µm in thickness are difficult to manage, they show no significant disadvantages compared to Ti or Be with molecular plating.

2-Propanol (isopropanol) as organic solvent has previously been used for the preparation of actinide targets on Ti and Be backings. But on Al, the stability of the U layer is not acceptable. The surface of most of the targets looked scaly or cracked associated with irreproducible plating yields. In order to solve these problems, an alternative solvent, 2-Methyl-1-Propanol (isobutanol) was tested. Table 1 compares the plating condition of the previously used isopropanol and the newly tested conditions applying isobutanol.

Table 1: Plating conditions for isopropanol and isobutanol (U on Al-Backing)

| Solvent  | Voltage  | Current  | Plating  | Thickn.           |
|----------|----------|----------|----------|-------------------|
|          | [V]      | [mA]     | time [h] | [µg/cm²]          |
| lso-     | 100-     |          |          | 390 <sup>#</sup>  |
| propanol | 1200     | 0.5 -3.0 | 1        | 390               |
|          | stepwise |          |          |                   |
| lso-     | 150 V    | 0.01-    | 4 - 5    | 650 <sup>##</sup> |
| butanol  | 150 V    | 0.5      | 4-5      | 050               |

The hydroscopic character of isopropanol might have been the reason for the poor surface quality since the plating solution as always been exposed to air for a couple of hours prior to the plating. The content of water may cause the relative high current and, thus, it possibly effects the formation of obstructing hydroxides at the surface of the Isobutanol, which is also used by backing foil. the target laboratory of the Lawrence Berkeley National Laboratory, LBNL, is less polar and therefore water-soluble [4]. During numerous poorly experiments, the plating conditions were adjusted to a lower voltage resulting in a longer plating time as shown in Table 1. With isobutanol, the coating looks more homogenous without visible cracks.

That has been approved with 25µm as well as 10µm Al backings. Fig 1 shows a light optical micrograph of an U-target, as usually prepared for the existing rotating actinide target wheel assembly at GSI.



Fig 1: Uranium on Al Backing (25µm), plated from isobutanol within 3 h, Voltage 150 V

Furthermore, for U, a time dependence of the depositions yield has been determined. So far, a maximum yield at about 60 - 65 % is reached at a plating time of 5 h, as shown in Fig 2. In future investigations, the work will also focus on an increase of deposition yield to 75 % or more as achieved with isopropanol.



Fig 2: Time dependence of deposition yield at molecular plating of U on 25μm Al backing (from isobutanol with 150 V)

Next we plan to apply these conditions to other elements, especially various lanthanides. Also, the use of autoradiography [5] and REM/EDX will be further investigated to monitor target thickness, homogeneity and surface layer composition, respectively.

## References

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<sup>\*</sup> F+E Vertrag Mz/JVK Entwicklung und Herstellung von Transuran- u. sonstigen radioaktiven Targets

<sup>#</sup> corresponds to 74% at an intake of 500µg U /cm<sup>2</sup>

<sup>##</sup> corresponds to 65% at an intake of 1000µg U/cm<sup>2</sup>